BLF6G15LS-250PBRN

Power LDMOS transistor

AMPLEON

Rev. 3 — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

250 W LDMOS power transistor for base station applications at frequencies from 1450 MHz to 1550 MHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25 \,^{\circ}$ C in a class-AB production test circuit.

Mode of operation	f	V _{DS}	P _{L(AV)}	Gp	η _D	ACPR
	(MHz)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	1476 to 1511	28	60	18.5	34.0	-30 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF per carrier. Carrier spacing 5 MHz.

1.2 Features and benefits

- Typical 2-carrier W-CDMA performance at frequencies of 1476 MHz and 1511 MHz, a supply voltage of 28 V and an I_{Dq} of 1410 mA:
 - ◆ Average output power = 60 W
 - ◆ Power gain = 18.5 dB
 - ◆ Efficiency = 34.0 %
 - ◆ ACPR = -30 dBc
- Easy power control
- Integrated ESD protection
- Enhanced ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (1450 MHz to 1550 MHz)
- Internally matched for ease of use
- Compliant to Restriction of Hazardous Substances (RoHS) Directive 2002/95/EC
- Integrated current sense

1.3 Applications

■ RF power amplifiers for GSM, GSM EDGE, CDMA and W-CDMA and multi carrier applications in the 1450 MHz to 1550 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
1	drain1		4 0	
2	drain2		$\begin{array}{cccccccccccccccccccccccccccccccccccc$	1 6, 7
3	gate1		5	3 - 8, 9
4	gate2		8 3 4 9	3
5	source	<u>[1]</u>		4 5
6, 7	sense drain			2 svm127
8, 9	sense gate			2 sym127

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package				
	Name	Description	Version			
BLF6G15LS-250PBRN	-	earless flanged LDMOST ceramic package; 8 leads	SOT1110B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V _{GS}	gate-source voltage		-0.5	+11	V
I _D	drain current		-	64	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C
T _{case}	case temperature		<u>[1]</u> _	150	°C

^[1] Continuous use at maximum temperature will affect MTTF.

5. Recommended operating conditions

Table 5. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
T _{case}	case temperature		-40	+125	°C

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-case)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 60 W (CW)	0.29	K/W

7. Characteristics

Table 7. Characteristics

 $T_i = 25$ °C per section; unless otherwise specified

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS} \\$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1.8 \text{ mA}$	65	75	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 180 mA	1.4	1.8	2.4	V
I _{Dq}	quiescent drain current	sense transistor:	1.31	1.41	1.51	Α
		I_{DS} = 20.1 mA; V_{DS} = 12 V				
		main transistor:				
		V_{DS} = 28 V				
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	25.3	29	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	280	nA
g _{fs}	forward transconductance	$V_{DS} = 10 \text{ V}; I_{D} = 9 \text{ A}$	8.1	12.3	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 6.3 \text{ A}$	0.03	0.1	0.16	Ω

8. Application information

Table 8. RF performance

Mode of operation: 2-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 DPCH; f_1 = 1473.4 MHz; f_2 = 1478.4 MHz; f_3 = 1508.4 MHz; f_4 = 1513.4 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1410 mA; T_{case} = 25 °C; unless otherwise specified in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$P_{L(AV)}$	average output power		-	60	-	W
Gp	power gain	$P_{L(AV)} = 60 \text{ W}$	16.5	18.5	-	dB
RLin	input return loss	$P_{L(AV)} = 60 \text{ W}$	-	-11	-7	dB
η_{D}	drain efficiency	$P_{L(AV)} = 60 \text{ W}$	31	34	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 60 \text{ W}$	-	-30	-27	dBc

Table 9. PAR performance

Mode of operation; 1-carrier W-CDMA; PAR 7.5 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 DPCH; f_1 = 1510.9 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1410 mA; T_{case} = 25 °C; unless otherwise specified in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
PAR _O	output peak-to-average ratio	P _{L(AV)} = 120 W at 0.01 % probability on CCDF	3.4	4.2	-	dB

8.1 Ruggedness in class-AB operation

The BLF6G15LS-250PBRN is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dg} = 1410 mA; P_L = 200 W; f = 1475 MHz.

8.2 Impedance information

Table 10. Typical impedance per section

 $I_{Dq} = 950 \text{ mA}$; main transistor $V_{DS} = 28 \text{ V}$

f	Z _S [1]	Z _L [1]
(MHz)	(Ω)	(Ω)
1480	1.1 – j2.8	2.3 – j3.2
1510	1.3 – j2.8	2.1 – j2.8

[1] Z_S and Z_L defined in Figure 1.

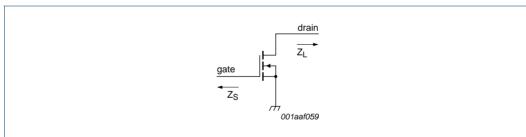
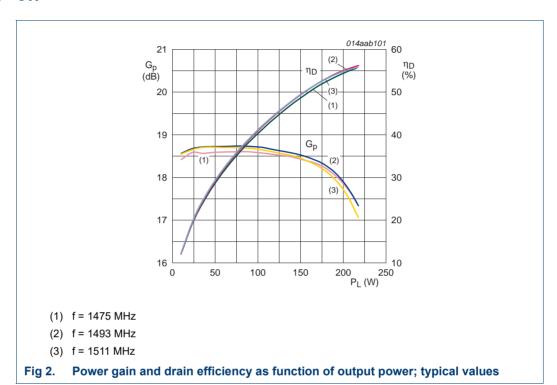


Fig 1. Definition of transistor impedance

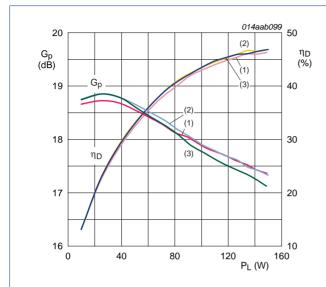
8.3 Graphs

8.3.1 CW



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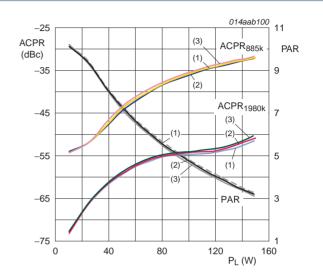
8.3.2 IS-95



IS-95: PAR = 9.8 dB at 0.01 % probability of the CCDF.

- (1) f = 1475 MHz
- (2) f = 1493 MHz
- (3) f = 1511 MHz

Fig 3. Power gain and drain efficiency as function of output power; typical values



IS-95: PAR = 9.8 dB at 0.01 % probability of the CCDF.

- (1) f = 1475 MHz
- (2) f = 1493 MHz
- (3) f = 1511 MHz

Fig 4. Adjacent channel power ratio and peak-to-average power ratio as function of output power; typical values

8.3.3 2-Carrier W-CDMA (5 MHz spacing)

RF performance sweep with 2-carrier W-CDMA is unavailable for the BLF6G15LS-250PBRN. The typical 2-carrier W-CDMA sweep of the BLF6G15L-250PBRN can be found in its data sheet.

9. Test information

Table 11. List of components
See Figure 5 for component layout.

Component	Description	Value	Remarks
C1, C2, C3, C4	multi layer ceramic chip capacitor	100 pF	<u>[1]</u>
C5, C6	multi layer ceramic chip capacitor	10 μF	[2]
C7	multi layer ceramic chip capacitor	10 nF	on input gate line as shown
C8	multi layer ceramic chip capacitor	100 nF	[2]
C10	multi layer ceramic chip capacitor	2.4 pF	<u>[1]</u>
C11	multi layer ceramic chip capacitor	3.6 pF	[3]
C12	electrolytic capacitor	470 μF; 63 V	
C13, C14, C15, C16	multi layer ceramic chip capacitor	33 pF	[3]
R1	chip resistor	3.9 kΩ	Philips 0603

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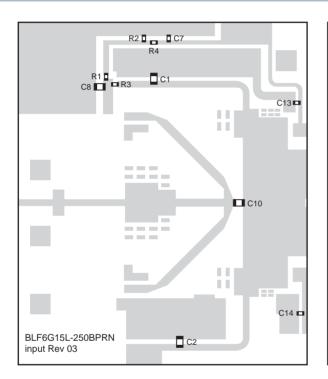
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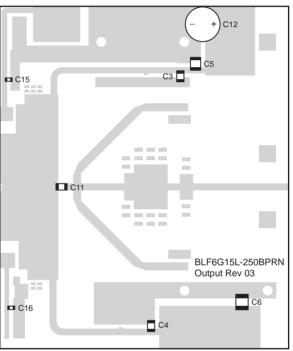
Table 11. List of components ... continued

See Figure 5 for component layout.

Component	Description	Value	Remarks
R2	chip resistor	2.2 kΩ	Philips 0603
R3	chip resistor	10 Ω	Philips 0603
R4	chip resistor	0 Ω	Philips 0603

- [1] American Technical Ceramics type 800B or capacitor of same quality.
- [2] TDK or capacitor of same quality.
- [3] American Technical Ceramics type 100B or capacitor of same quality.





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Printed-Circuit Board (PCB): Taconic RF-35A2; ϵ_r = 3.5 F/m; thickness = 0.762 mm; thickness copper plating = 35 μ m.

The vias can be as a reference to place components.

The above layout shows the test circuit used to measure the devices in production. A more appropriate application demonstration for specific customer needs can be provided.

See Table 11 for list of components.

Fig 5. Component layout

10. Package outline

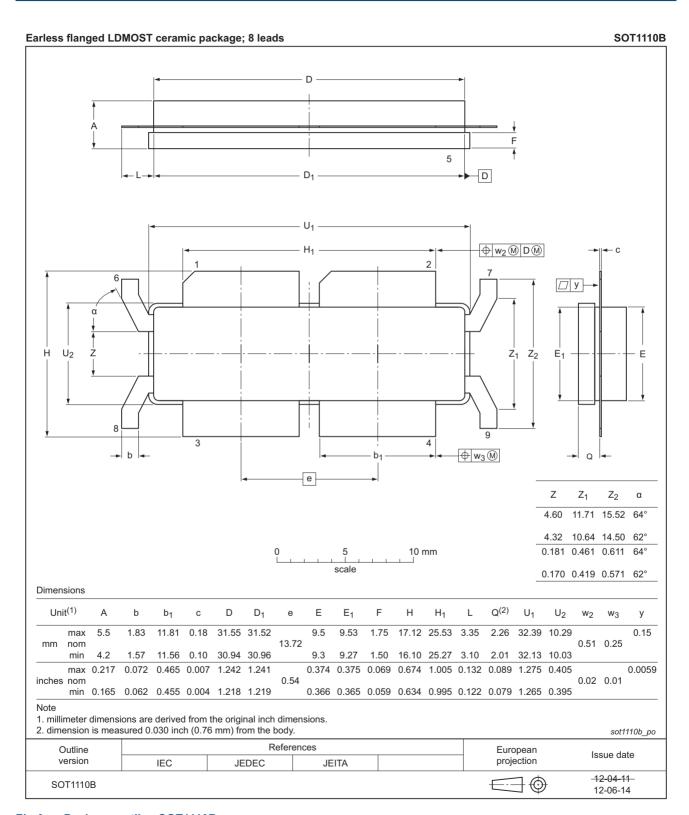


Fig 6. Package outline SOT1110B

11. Abbreviations

Table 12. Abbreviations

Acronym	Description			
CCDF	Complementary Cumulative Distribution Function			
CDMA	Code Division Multiple Access			
CW	Continuous Wave			
DPCH	Dedicated Physical CHannel			
EDGE	Enhanced Data rates for GSM Evolution			
ESD	ElectroStatic Discharge			
GSM	Global System for Mobile communications			
IS-95	Interim Standard 95			
LDMOS	Laterally Diffused Metal-Oxide Semiconductor			
LDMOST	Laterally Diffused Metal-Oxide Semiconductor Transistor			
MTTF	Mean Time To Failure			
PAR	Peak-to-Average Ratio			
VSWR	Voltage Standing-Wave Ratio			
W-CDMA	Wideband Code Division Multiple Access			

12. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF6G15LS-250PBRN#3	20150901	Product data sheet	-	BLF6G15LS-250PBRN v.2	
Modifications:	The format of this document has been redesigned to comply with the new identity guidelines of Ampleon.				
	Legal texts have been adapted to the new company name where appropriate.				
BLF6G15LS-250PBRN v.2	20120718	Product data sheet	-	BLF6G15LS-250PBRN v.1	
BLF6G15LS-250PBRN v.1	20120611	Product data sheet	-	-	

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13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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